(For candidates admitted from 2016–2017 onwards)

U.G. DEGREE EXAMINATION, APRIL 2022.

Part IV — Electronics — Non-Major Elective

PRINCIPLES OF ELECTRONICS

Time: Three hours

Maximum: 75 marks

PART A — $(10 \times 2 = 20)$

Answer ALL questions.

- What is Fixed Resistor? List out its types.
- 2 Draw the symbol of capacitor and inductor.
- ω Define Extrinsic semiconductor.
- What is a PN junction?
- 5 transistors. Draw the current symbols of a NPN and PNP
- 6 configuration. Define input characteristics of a common Emitter
- .7 Define the term Transfer characteristics of JFET.

- 8. List the advantages of FET over bipolar transistor.
- Define Bidirectional thyristors.
- 10. Give any two application of TRIAC.

PART B —
$$(5 \times 5 = 25)$$

Answer ALL questions, choosing either (a) or (b).

11. (a) Describe the important specifications of resistor.

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- (b) What are the different types of inductors? Give some important applications of inductors.
- 12. (a) What is meant by Intrinsic semiconductor.

Or

- (b) Explain forward characteristics of PN junction diode.
- 13. (a) With the neat diagram explain the construction of NPN transistor.

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(b) Define the input and output characteristics of CE transistor.

14. (a) Explain the construction of JFET with the neat diagram.

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- (b) Briefly explain structure of a depletion type MOSFET.
- 15. (a) Explain four modes of TRIAC operation.

Or

(b) List out some application of DIAC. PART C — $(3 \times 10 = 30)$

Answer any THREE questions.

Briefly explain the types of fixed capacitor

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- 17. With the neat energy band diagram explain the P-type semiconductor.
- 18. Describe the operation of PNP transistor.
- 19. Define the following terms of a JFET.
- (a) The pinch off voltage
- (b) Channel ohmic region
- (c) Drain resistance
- (d) Transconductance
- (e) I_{DSS}
- 20. Explain the construction and working of a DIAC.